



## 0.8A SURFACE MOUNT GLASS PASSIVATED BRIDGE RECTIFIER

### FEATURES:

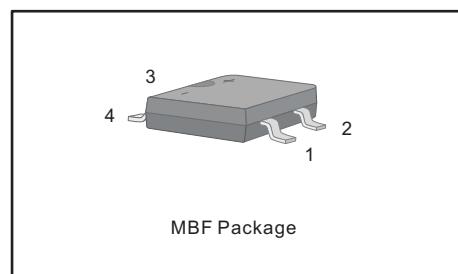
- Glass Passivated Chip Junction
- Reverse Voltage - 100 to 1000 V
- Forward Current - 0.8 A
- High Surge Current Capability
- Designed for Surface Mount Application

### PINNING

PIN	DESCRIPTION
1	Input Pin ( ~ )
2	Input Pin ( ~ )
3	Output Anode ( + )
4	Output Cathode ( - )

### MECHANICAL DATA

- Case: MBF
- Terminals: Solderable per MIL-STD-750, Method 2026
- Approx. Weight: 75mg 0.0026oz



### Maximum Ratings and Electrical characteristics

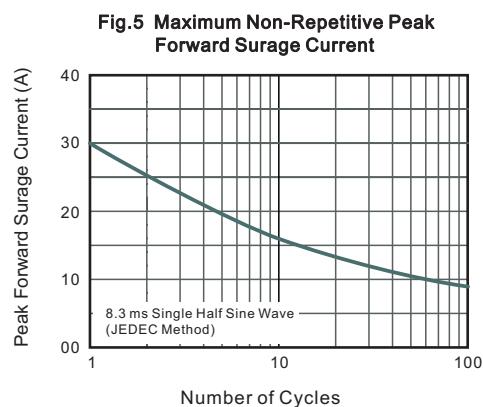
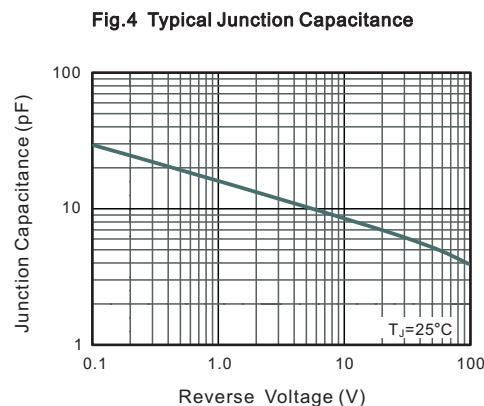
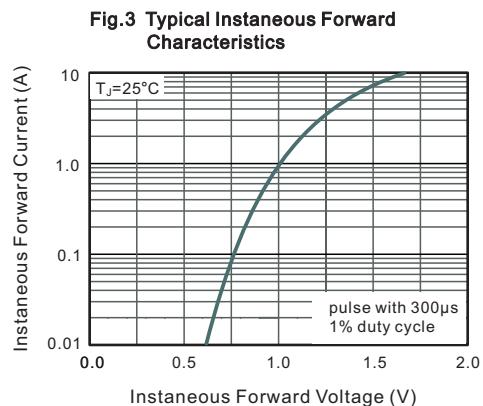
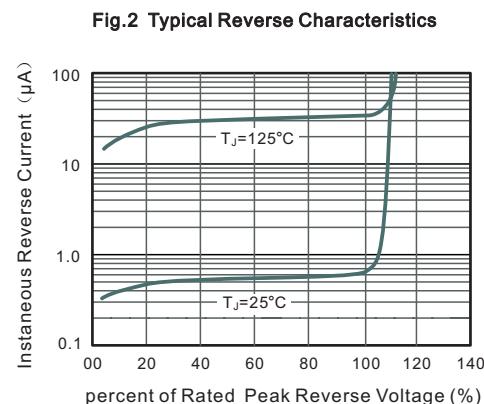
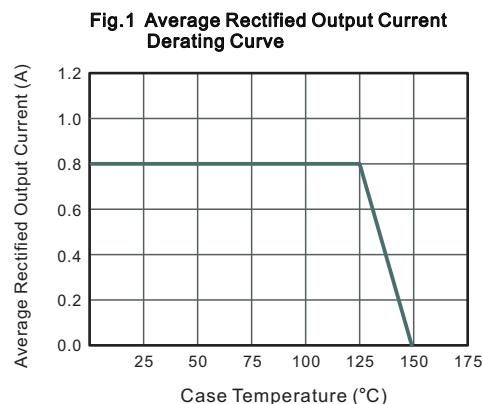
Ratings at 25 °C ambient temperature unless otherwise specified.

Single phase half-wave 60 Hz, resistive or inductive load, for capacitive load current derate by 20 %.

Parameter	Symbols	MB1F	MB2F	MB4F	MB6F	MB8F	MB10F	Units
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	100	200	400	600	800	1000	V
Maximum RMS voltage	$V_{RMS}$	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	$V_{DC}$	100	200	400	600	800	1000	V
Average Rectified Output Current at $T_c = 125^\circ\text{C}$	$I_o$	0.8						A
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load (JEDEC Method)	$I_{FSM}$	30						A
Maximum Forward Voltage at 0.8 A	$V_F$	1.1						V
Maximum DC Reverse Current @ $T_A = 25^\circ\text{C}$ @ $T_A = 125^\circ\text{C}$	$I_R$	5 40						$\mu\text{A}$
Typical Junction Capacitance ( Note1 )	$C_j$	13						pF
Typical Thermal Resistance ( Note2 )	$R_{\theta JA}$ $R_{\theta JC}$	90 30						°C/W
Operating and Storage Temperature Range	$T_j, T_{stg}$	-55 ~ +150						°C

Note: 1. Measured at 1MHz and applied reverse voltage of 4 V D.C.

2. Mounted on glass epoxy PC board with 4×1.5"×1.5" ( 3.81×3.81 cm ) copper pad.

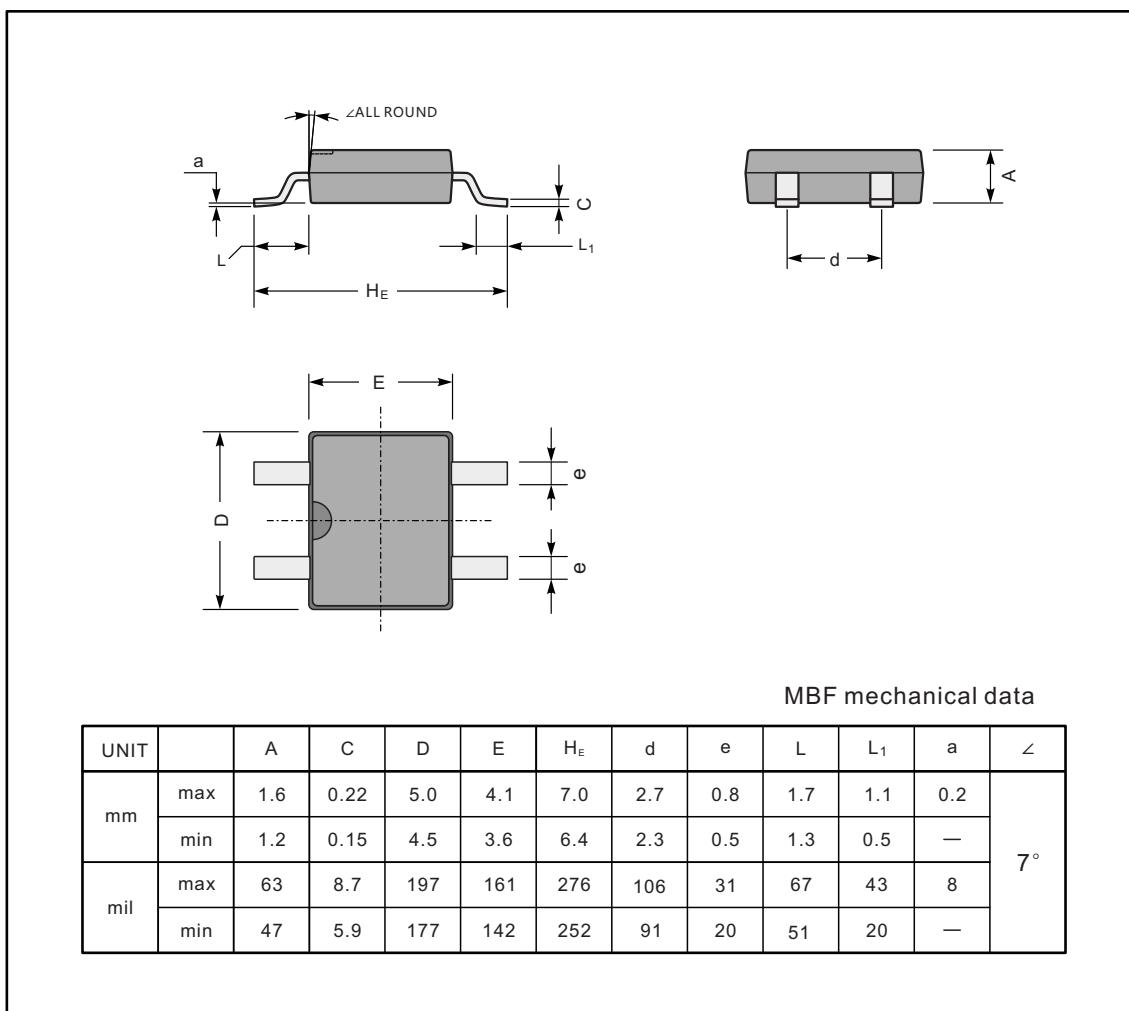




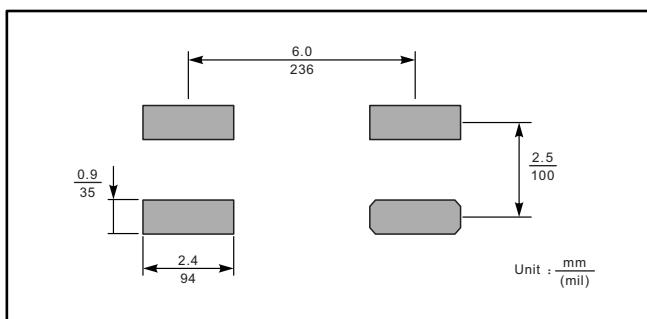
## PACKAGE OUTLINE

Plastic surface mounted package; 4 leads

MBF



### The recommended mounting pad size



### Marking

Type number	Marking code
MB1F	MB1F
MB2F	MB2F
MB4F	MB4F
MB6F	MB6F
MB8F	MB8F
MB10F	MB10F